

PUMB3

50 V, 100 mA PNP/PNP resistor-equipped transistor; R1 = 4.7 k Ω , R2 = open

24 May 2023

Product data sheet

1. General description

PNP/PNP Resistor-Equipped Transistor (RET) in a very small SOT363 (SC-88) Surface-Mounted Device (SMD) plastic package.

NPN/PNP complement: PUMD6 NPN/NPN complement: PUMH7

2. Features and benefits

- Built-in bias resistors
- · Simplifies circuit design
- · Reduces component count
- Reduces pick and place costs
- AEC-Q101 qualified

3. Applications

- · Low current peripheral driver
- Controlling IC inputs
- · Replaces general-purpose transistors in digital applications

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor	er transistor						
V _{CEO}	collector-emitter voltage	open base		-	-	-50	V
Io	output current			-	-	-100	mA
R1	bias resistor 1 (input)			3.3	4.7	6.1	kΩ



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5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	GND1	GND (emitter) TR1		O1 I2 GND2
2	I1	input (base) TR1	□6 □5 □4	
3	O2	output (collector) TR2		R1 L
4	GND2	GND (emitter) TR2		TR1
5	12	input (base) TR2	H ₁ H ₂ H ₃	R1
6	01	output (collector) TR1	TSSOP6 (SOT363)	GND1 I1 O2 006aaa268

6. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
PUMB3		plastic, surface-mounted package; 6 leads; 0.65 mm pitch; 2.1 mm x 1.25 mm x 0.95 mm body	<u>SOT363</u>		

7. Marking

Table 4. Marking codes

Type number	Marking code[1]
PUMB3	B5%

[1] % = placeholder for manufacturing site code

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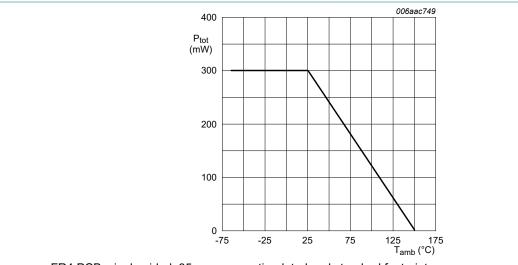
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transistor	,		•			
V _{CBO}	collector-base voltage	open emitter		-	-50	V
V _{CEO}	collector-emitter voltage	open base		-	-50	V
V _{EBO}	emitter-base voltage	open collector		-	-5	V
Io	output current			-	-100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	200	mW
Per device			•			
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	300	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-65	150	°C
T _{stg}	storage temperature			-65	150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided, 35 µm copper, tin-plated and standard footprint.



FR4 PCB, single-sided, 35 µm copper, tin-plated and standard footprint

Fig. 1. Per device: Power derating curve

50 V, 100 mA PNP/PNP resistor-equipped transistor; R1 = 4.7 k Ω , R2 = open

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor	er transistor						
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	625	K/W
Per device							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	416	K/W

[1] Device mounted on an FR4 PCB, single-sided, 35 µm copper, tin-plated and standard footprint.

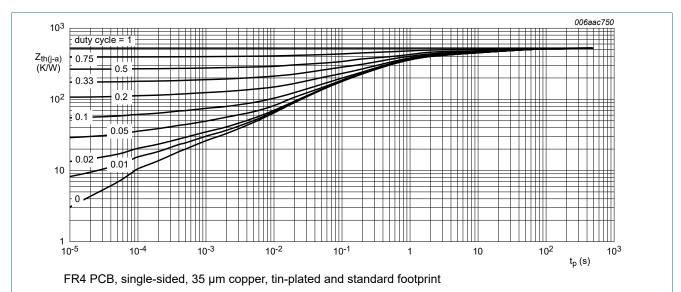


Fig. 2. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

50 V, 100 mA PNP/PNP resistor-equipped transistor; R1 = 4.7 k Ω , R2 = open

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per transiste	or					
V _{(BR)CBO}	collector-base breakdown voltage	$I_C = -100 \mu A; I_E = 0 A; T_{amb} = 25 °C$	-50	-	-	V
$V_{(BR)CEO}$	collector-emitter breakdown voltage	$I_C = -2 \text{ mA}; I_B = 0 \text{ A}; T_{amb} = 25 \text{ °C}$	-50	-	-	V
I _{CBO}	collector-base cut-off current	V _{CB} = -50 V; I _E = 0 A; T _{amb} = 25 °C	-	-	-100	nA
I _{CEO}	collector-emitter cut-off	V _{CE} = -30 V; I _B = 0 A; T _{amb} = 25 °C	-	-	-100	nA
	current	V _{CE} = -30 V; I _B = 0 A; T _j = 150 °C	-	-	-5	μA
I _{EBO}	emitter-base cut-off current	V _{EB} = -5 V; I _C = 0 A; T _{amb} = 25 °C	-	-	-100	nA
h _{FE}	DC current gain	V_{CE} = -5 V; I_{C} = -1 mA; T_{amb} = 25 °C	200	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_C = -5 \text{ mA}$; $I_B = -0.25 \text{ mA}$; $T_{amb} = 25 ^{\circ}\text{C}$	-	-	-100	mV
R1	bias resistor 1 (input)		3.3	4.7	6.1	kΩ
C _c	collector capacitance	V _{CB} = -10 V; I _E = 0 A; i _e = 0 A; f = 1 MHz; T _{amb} = 25 °C	-	-	3	pF

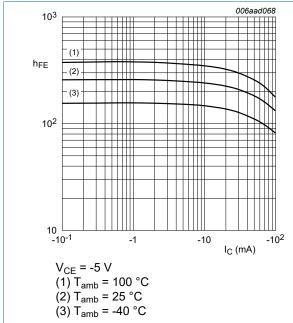


Fig. 3. DC current gain as a function of collector current; typical values

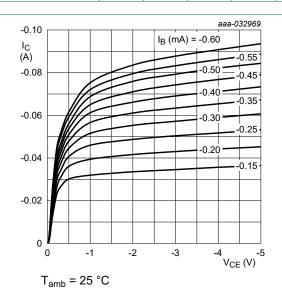
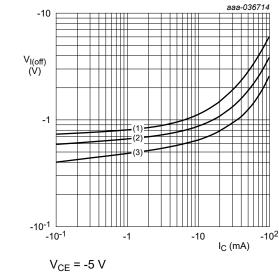


Fig. 4. Collector current as a function of collectoremitter voltage; typical values

50 V, 100 mA PNP/PNP resistor-equipped transistor; R1 = 4.7 k Ω , R2 = open



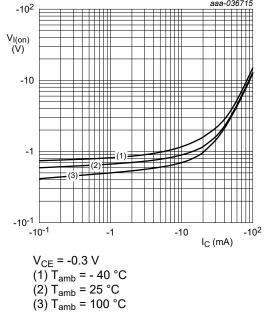
$$V_{CE} = -5 V$$

(1) $T_{amb} = -40 °C$

$$(1) I_{amb} = -40 °C$$

$$(3) T_{amb} = 100 °C$$



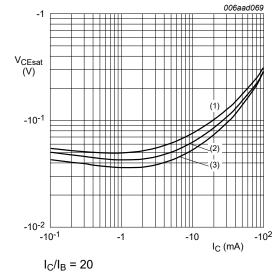


$$(1) T_{amb} = -40 ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

$$(3) T_{amb} = 100 °C$$

On-state input voltage as a function of collector current; typical values



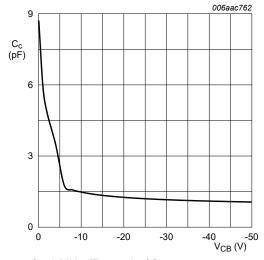
$$I_{\rm C}/I_{\rm B} = 20$$

(1)
$$T_{amb}$$
 = 100 °C

$$(2) T_{amb} = 25 °C$$

(3)
$$T_{amb} = -40 \, ^{\circ}C$$

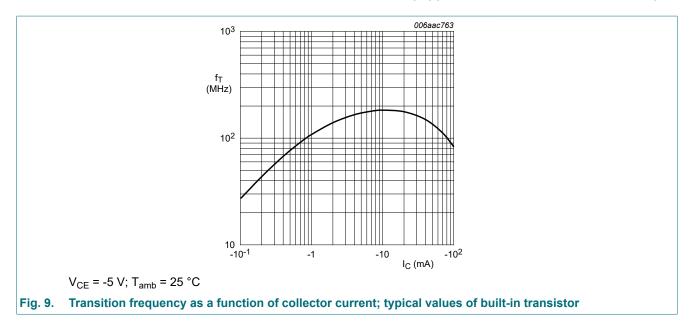
Fig. 7. Collector-emitter saturation voltage as a function of collector current; typical values



 $f = 1 \text{ MHz}; T_{amb} = 25 \text{ °C}$

Collector capacitance as a function of collector-Fig. 8. base voltage; typical values

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11. Test information

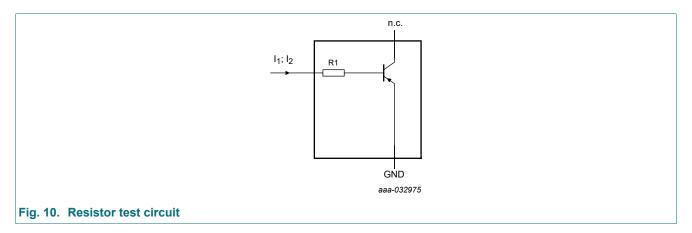
Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

Resistor calculation

• Calculation of bias resistor 1 (R1)

$$R_{I} = \frac{V(I_{2}) - V(I_{1})}{I_{2} - I_{1}}$$



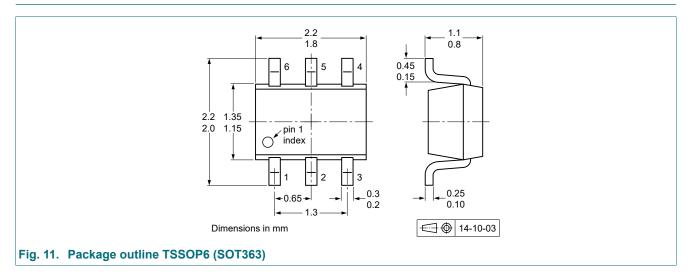
Resistor test conditions

Table 8. Resistor test conditions

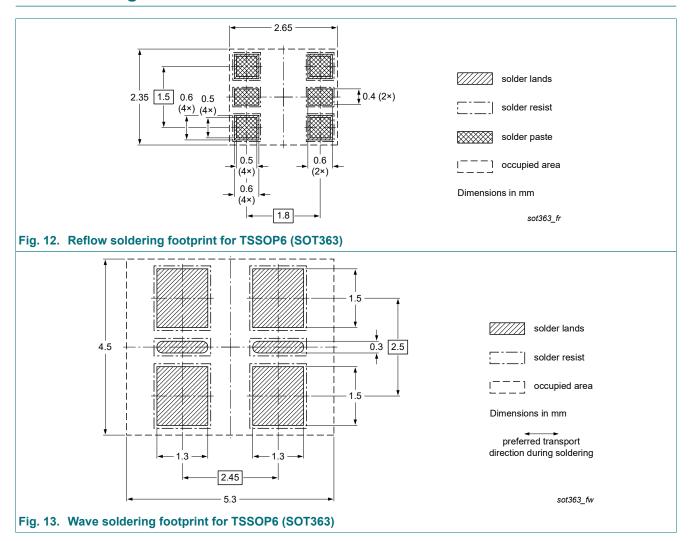
Type number	R1 (kΩ)	R2 (kΩ)	Test conditions	
			I ₁	l ₂
PUMB3	4.7	open	-600 μA	-700 μΑ

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12. Package outline



13. Soldering



Nexperia

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14. Revision history

Table 9. Revision history

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Data sheet ID	Release date	Data sheet status	Change notice	Supersedes	
PUMB3 v.3	20230524	Product data sheet	-	PUMB3_PEMB3 v.2	
Modifications:	 The format of this data sheet has been redesigned to comply with the identity guidelines Nexperia. Legal texts have been adapted to the new company name where appropriate. Family data sheet reduced to single type data sheet. Packing information is removed. 				
PUMB3_PEMB3 v.2	20031015	Product data sheet	-	PUMB3_PEMB3 v.1	
PUMB3_PEMB3 v.1	20010919	Product specification	-	-	

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15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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